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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR

 μ PA1930

P-CHANNEL MOSFET FOR SWITCHING

DESCRIPTION

The μ PA1930 is a P-channel MOSFET designed for power switch of portable machine and so on.

FEATURES

-4.5 V drive available

RDS(on)1 = 77 m Ω MAX. (Vgs = -10 V, ID = -2.5 A) RDS(on)2 = 100 m Ω MAX. (VGS = -4.5 V, ID = -2.5 A)

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA1930TE-T1-A	SC-95 (Mini Mold Thin Type)
μPA1930TE-T2-A	

Remark "-A" indicates Pb-free (This product does not contain Pb in external electrode and other parts).

> "-T1", "-T2" indicates the unit orientation (8 mm embossed carrier tape, 3,000 pcs/reel).

Marking: UA

ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0V)	VDSS	-30	V
Gate to Source Voltage (Vps = 0V)	Vgss	∓20	V
Drain Current (DC) Note1	$I_{D(DC)}$	∓4.5	Α
Drain Current (pulse) Note2	ID(pulse)	∓18	Α
Total Power Dissipation	P _{T1}	0.2	W
Total Power Dissipation Note1	P _{T2}	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C

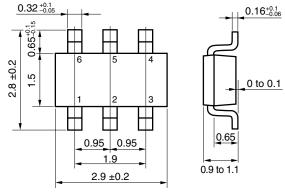
- **Notes 1.** Mounted on FR-4 Board 2500 mm² \times 1.6 mm, $t \le 5$ sec
 - **2.** PW \leq 10 μ s, Duty Cycle \leq 1%

Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

Caution This product is electrostatic-sensitive device due to low ESD capability and should be handled with caution for electrostatic discharge. V_{ESD} \pm 150 V TYP. (C = 200 pF, R = 0 Ω , Single pulse)

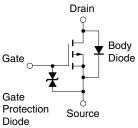
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PACKAGE DRAWING (Unit : mm)



1, 2, 5, 6 : Drain : Gate 3 : Source

EQUIVALENT CIRCUIT

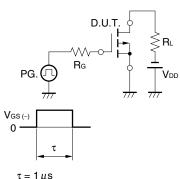


ELECTRICAL CHARACTERISTICS (TA = 25°C)

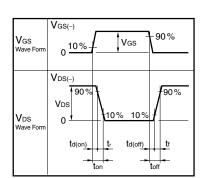
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -30 V, V _{GS} = 0 V			-1	μА
Gate Leakage Current	Igss	$V_{GS} = \mp 16 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μА
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 \text{ V}, I_{D} = -1.0 \text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance Note	yfs	$V_{DS} = -10 \text{ V}, \text{ ID} = -2.5 \text{ A}$	1			S
Drain to Source On-state Resistance Note	RDS(on)1	V _G s = -10 V, I _D = -2.5 A		58	77	mΩ
	RDS(on)2	$V_{GS} = -4.5 \text{ V}, I_{D} = -2.5 \text{ A}$		77	100	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V		325		pF
Output Capacitance	Coss	V _G S = 0 V		78		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		65		pF
Turn-on Delay Time	td(on)	$V_{DD} = -15 \text{ V}, \text{ ID} = -2.5 \text{ A},$		8.5		ns
Rise Time	tr	V _G S = -10 V,		3.5		ns
Turn-off Delay Time	td(off)	$R_G = 6 \Omega$		33		ns
Fall Time	tr			19.5		ns
Total Gate Charge	Qg	V _{DD} = −24 V,		7.5		nC
Gate to Source Charge	Qgs	$V_{GS} = -10 \text{ V},$		1.1		nC
Gate to Drain Charge	Q _{GD}	$I_{D} = -4.5 \text{ A}$		2.3		nC
Diode Forward Voltage Note	V _{F(S-D)}	I _F = 4.5 A, V _{GS} = 0 V		0.93		V

Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME



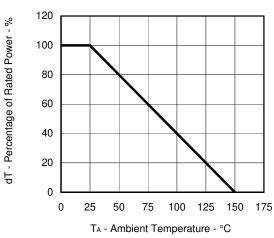




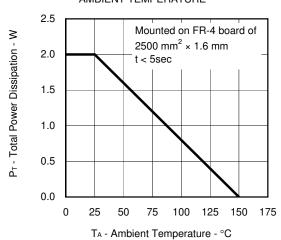
TEST CIRCUIT 2 GATE CHARGE

TYPICAL CHARACTERISTICS (TA = 25°C)

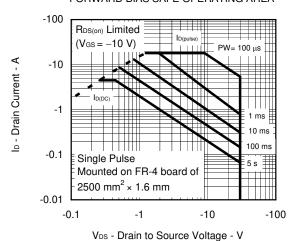
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



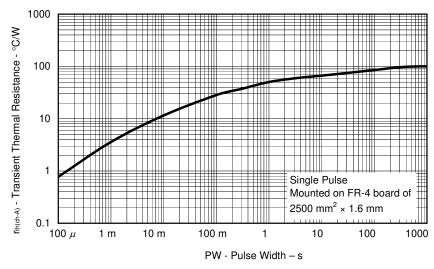
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



FORWARD BIAS SAFE OPERATING AREA



TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

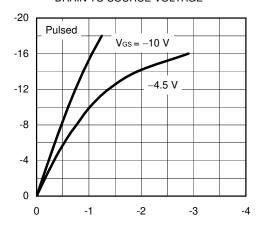


3

Ip - Drain Current - A

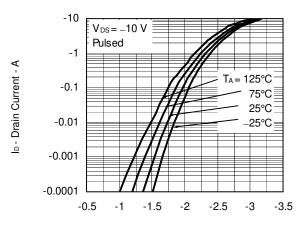
VGS(off) - Gate Cut-off Voltage - V

DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



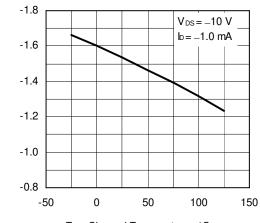
 $V_{\text{\scriptsize DS}}$ - Drain to Source Voltage - V

FORWARD TRANSFER CHARACTERISTICS



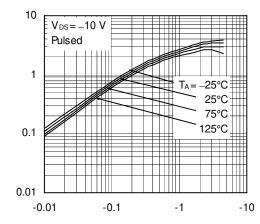
V_{GS} - Gate to Source Voltage - V

GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



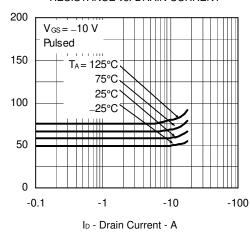
Tch - Channel Temperature - °C

FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT

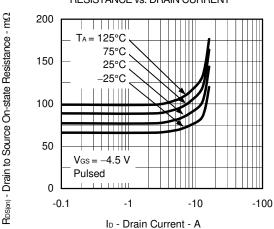


ID - Drain Current - A

DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



RDS(m) - Drain to Source On-state Resistance - mΩ

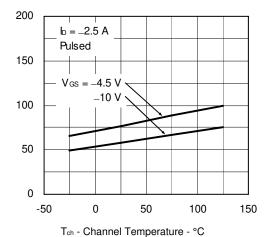
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| yts | - Forward Transfer Admittance -

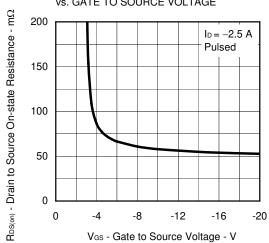
RDS(m) - Drain to Source On-state Resistance - mΩ

Ciss, Coss, Crss - Capacitance - pF

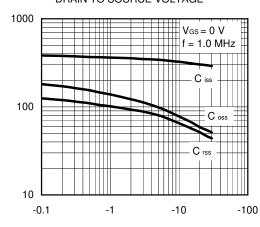
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



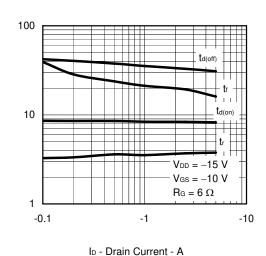
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



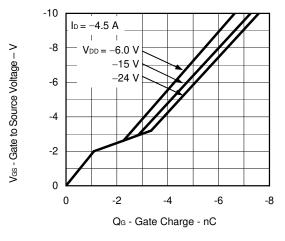
SWITCHING CHARACTERISTICS



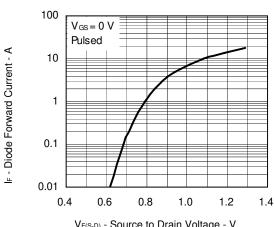
V_{DS} - Drain to Source Voltage - V

ta(on), tr, ta(off), tr - Switching Time - ns

DYNAMIC INPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



NEC μ PA1930

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